

DESCRIPTION

The ESD0801PB a low-capacitance Transient Voltage Suppressor (TVS) designed to provide electrostatic discharge (ESD) protection for data, control or power lines. With typical capacitance of 8pF only, The ESD0801PB designed to protect parasitic-sensitive systems against over-voltage and over-current transient events. It complies with IEC 61000-4-2 (ESD), Level 4 ($\pm 15\text{kV}$ air, $\pm 8\text{kV}$ contact discharge), IEC 61000-4-4 (electrical fast transient - EFT) (40A, 5/50 ns), very fast charged device model (CDM) ESD and cable discharge event (CDE), etc.

The ESD0801PB uses ultra-small DFN1006 package. The ESD0801PB device can protect one data line. It offers system designers flexibility to protect single data line where space is a premium concern.

ORDERING INFORMATION

Package: DFN1006

Material: RoHS compliant, Halogen free

Packing: Tape & Reel

Quantity per reel: 10,000pcs

FEATURES

- Transient protection for high-speed data lines IEC 61000-4-2 (ESD) $\pm 15\text{kV}$ (Air) $\pm 8\text{kV}$ (Contact)
- IEC 61000-4-4 (EFT) 40A (5/50 ns)
- Cable Discharge Event (CDE)
- Package optimized for high-speed lines — Ultra-small package (1.0mm-0.6mm-0.4mm) — Protects one data, control or power line — Low capacitance
- Low leakage current
- Low clamping voltage
- Each I/O pin can withstand over 1000 ESD strikes for $\pm 8\text{kV}$ contact discharge

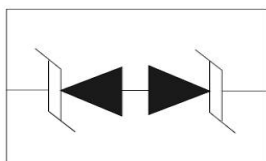
MACHANICAL DATA

- DFN1006 package —
- Flammability Rating: UL 94V-0
- Packaging: Tape and Reel
- High temperature soldering guaranteed: $260^{\circ}\text{C}/10\text{s}$ — Reel size: 7 inch

APPLICATIONS

- Portable Electronics
- Desktops, Servers and Notebooks
- Cellular Phones
- MP3 Ports
- Digital Ports
- Subscriber Identity Module (SIM) card

CIRCUIT DIAGRAM



PIN CONFIGURATION



ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Units
P _{PP}	Peak Pulse Power (8/20μs)	100	W
T _j	Operating Temperature	-55/+125	°C
T _{STG}	Storage Temperature	-55/+150	°C

ELECTRICAL CHARACTERISTICS (T_{amb}=25°C)

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
V _{RWM}	Reverse Stand-Off Voltage				5.0	V
V _{BR}	Reverse Breakdown voltage	I _T =1mA	6.0			V
I _R	Reverse leakage current.	V _{RWM} =5V			1	μA
I _{PP}	Peak Pulse Current	t _p =8/20us			5	A
V _C	Clamping Voltage	I _{PP} =1A, t _p =8/20us I _{PP} =5A, t _p =8/20us		13	9.5 15	V
C _J	Junction Capacitance	V _R =0V, f=1MHz		8	15	pF

ELECTRICAL CHARACTERISTICS CURVE

Figure 1: Peak Pulse Power Vs Pulse Time

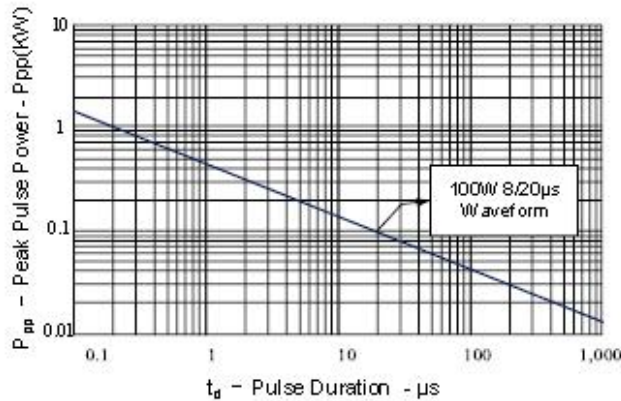


Figure 2: Power Derating Curve

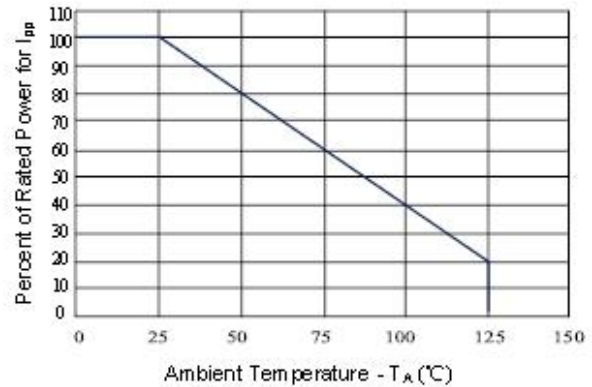


Figure 3: Clamping Voltage vs. Peak Pulse Current

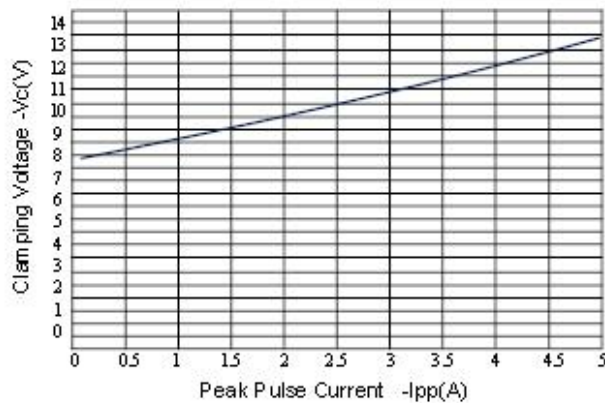


Figure 4: Normalized Junction Capacitance vs. Reverse Voltage

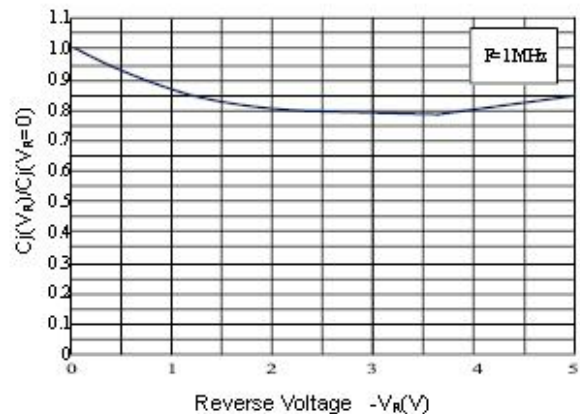


Figure 5: Pulse Waveform

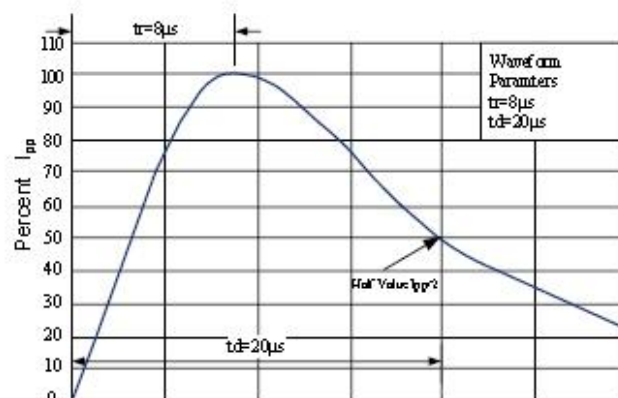
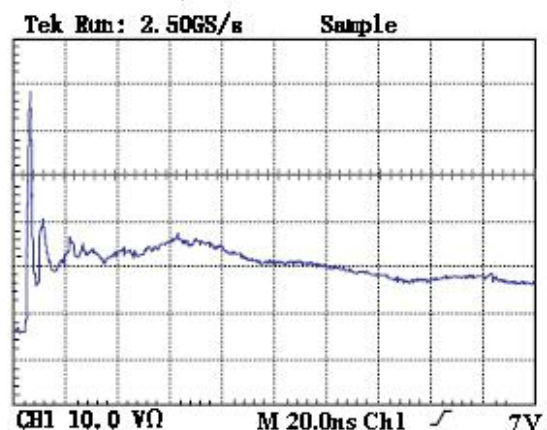
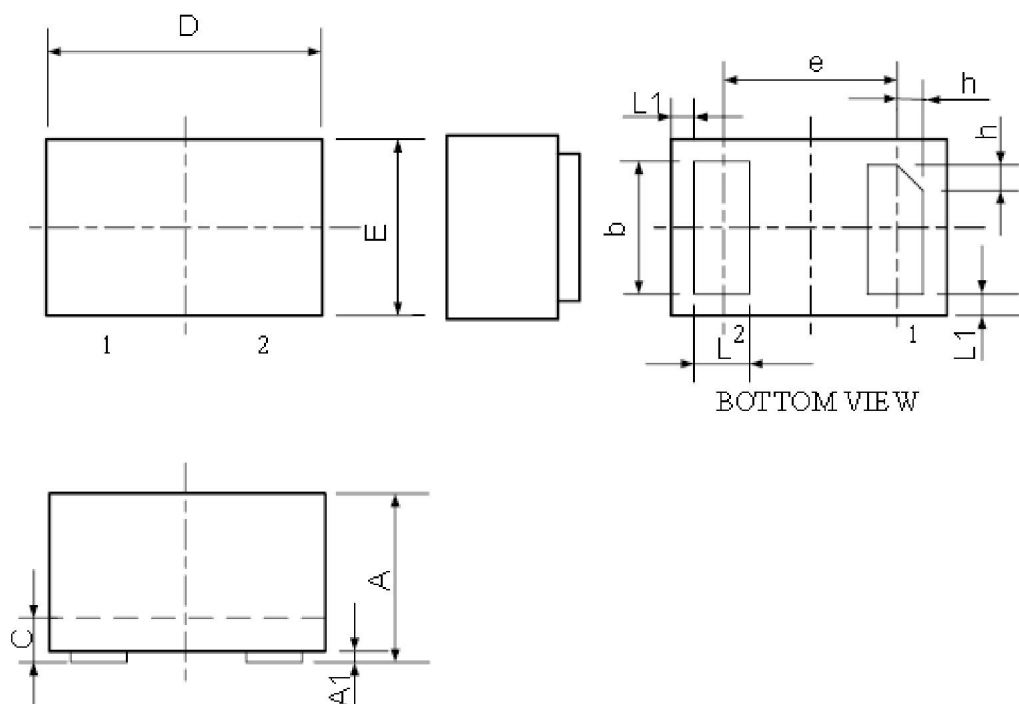


Figure 6: ESD Clamping(8kV Contact per IEC 61000-4-2)



DFN1006 PACKAGE OUTLINE DIMENSIONS


Symbol	Dimensions In Millimeters	
	Minimum	Maximum
A	0.450	0.550
A1	0.000	0.050
b	0.45	0.55
C	0.12	0.18
D	0.950	1.050
e	0.65BSC	
E	0.550	0.650
L	0.200	0.300
L1	0.05REF	
h	0.07	0.17